

**TYPE  
NAME**

**ML701B8R,ML725B8F,ML725C8F  
ML720J8S,ML720K8S**

**DESCRIPTION**

ML7XX8 series are InGaAsP laser diodes which provides a stable, single transverse mode oscillation with emission wavelength of 1310nm and standard continuous light output of 10mW.

ML7XX8 are hermetically sealed devices having the photodiode for optical output monitoring. This high-performance, high reliability, and long-life laser diode is suitable for such applications as the light sources for long-distance optical communication systems.

**FEATURES**

- 1310nm typical emission wavelength
- Low threshold current, low operating current
- High-power, wide temp. range operation  
( $P_o=10mW, T_c=-40\sim+85^{\circ}C$ )
- High reliability, long operation life
- Have a lens-cap  
(ML725C8F,ML720K8S)
- MQW\* active layer  
\* : Multiple Quantum Well

**APPLICATION**

Optical communication system

**ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Conditions	Ratings (Note1)	Unit
P <sub>O</sub>	Light output power	—	10 [7]	mW
V <sub>RL</sub>	Reverse Voltage (Laser diode)	—	2	V
V <sub>RD</sub>	Reverse Voltage (Photodiode)	—	20	V
I <sub>FD</sub>	Forward current (Photodiode)	—	2	mA
T <sub>c</sub>	Case temperature	—	-40~+85	°C
T <sub>stg</sub>	Storage temperature	—	-40~+100	°C

**ELECTRICAL/OPTICAL CHARACTERISTICS (T<sub>c</sub> = 25°C)**

Symbol	Parameter	Test conditions	Limits (Note1)			Unit
			Min.	Typ.	Max.	
I <sub>th</sub>	Threshold current	CW	—	5	15	mA
I <sub>OP</sub>	Operating current	CW,P <sub>O</sub> = 5mW	—	20	35	mA
V <sub>OP</sub>	Operating voltage	CW,P <sub>O</sub> = 5mW	—	1.1	1.5	V
η	Slope efficiency	CW,P <sub>O</sub> = 5mW	0.3 [0.2]	0.5 [0.35]	—	mW/mA
λ <sub>c</sub>	Center wavelength	CW,P <sub>O</sub> = 5mW	1290	1310	1330	nm
Δλ	Spectral width (RMS)	CW,P <sub>O</sub> = 5mW	—	1	2	nm
θ <sub>  </sub>	Beam divergence angle (parallel)	CW,P <sub>O</sub> = 5mW	—	25 [11]	—	deg.
θ <sub>⊥</sub>	Beam divergence angle (perpendicular)	CW,P <sub>O</sub> = 5mW	—	30 [11]	—	deg.
t <sub>r</sub> ,t <sub>f</sub>	Rise and fall times	I <sub>F</sub> = I <sub>th</sub> ,P <sub>O</sub> = 5mW,10~90%	—	0.3	0.7	ns
I <sub>m</sub>	Monitoring output current (Photodiode)	CW,P <sub>O</sub> = 5mW,V <sub>RD</sub> = 1V	0.1	0.5	—	mA
I <sub>D</sub>	Dark current (Photodiode)	V <sub>RD</sub> = 10V	—	0.01	0.1	μA
C <sub>t</sub>	Capacitance (Photodiode)	V <sub>RD</sub> = 10V,f = 1MHz	—	10	20	pF
P <sub>f</sub> (Note 2)	Fiber coupled power	CW,P <sub>O</sub> = 5mW,SI10/125	[0.4]	[0.8]	[—]	mW
D <sub>f</sub> (Note 3)	Fiber coupled distance	CW,P <sub>O</sub> = 5mW,SI10/125 (Note 3)	[5.0]	[5.8]	[6.2]	mm

Note 1 : Limits in [ ] applied to the lens-cap type.

Note 2 : P<sub>f</sub>,D<sub>f</sub> are applied to the lens-cap type.

Note 3 : D<sub>f</sub> is a distance from the reference plane to the fiber.

MITSUBISHI LASER DIODES  
ML7XX8 SERIES

InGaAsP —MQW—FP LASER DIODES

TYPICAL CHARACTERISTICS

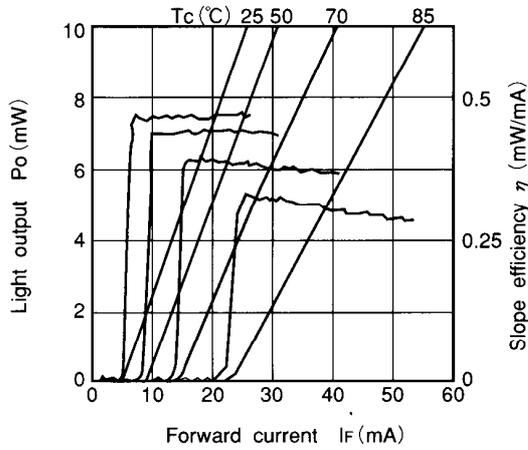


Fig.1 Light output vs. forward current

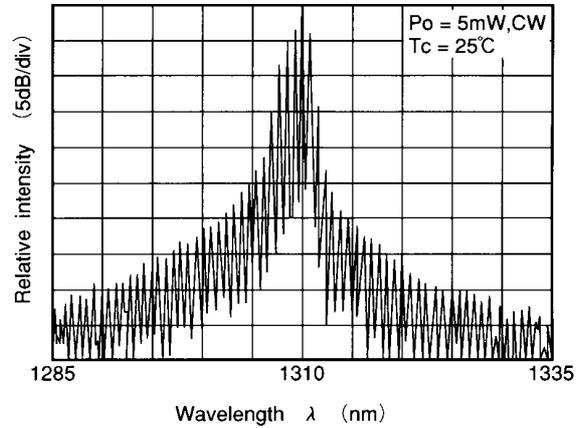


Fig.52 Spectrum

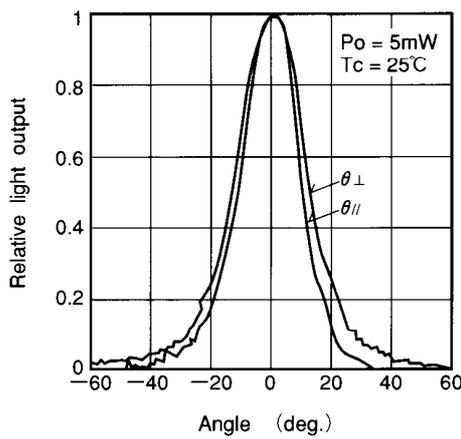


Fig.3 Far field pattern

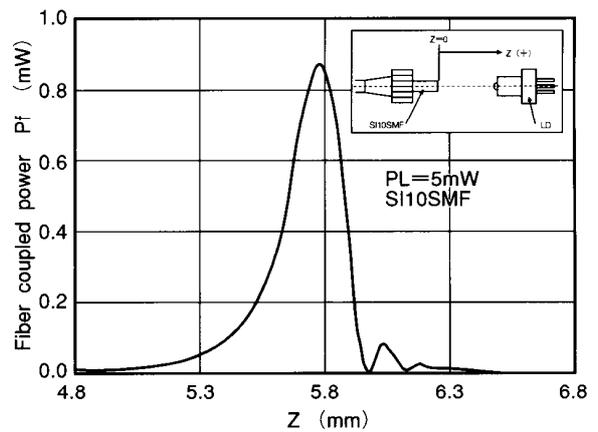
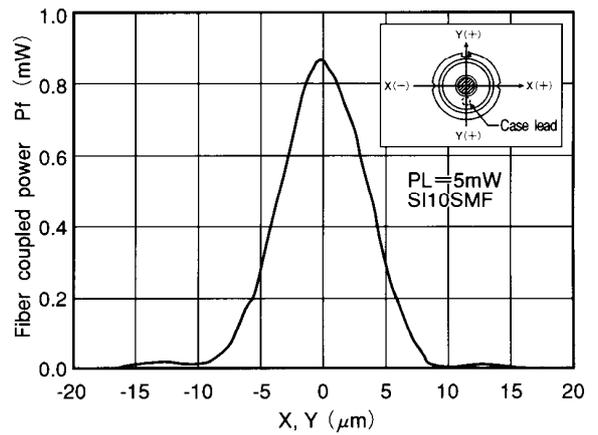
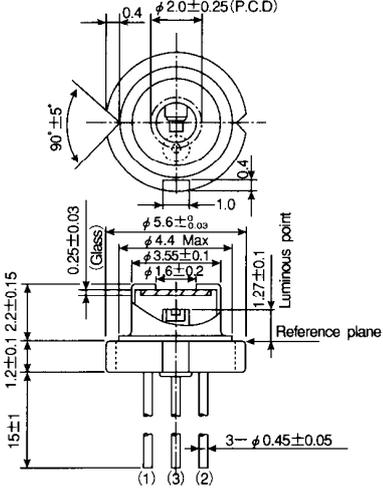
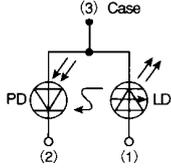
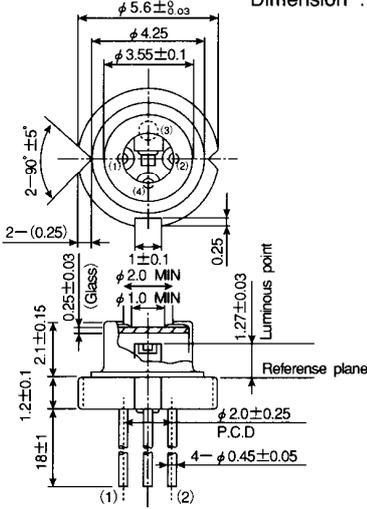
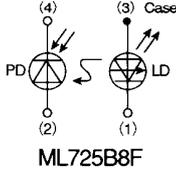
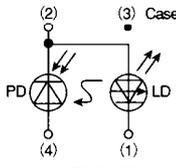
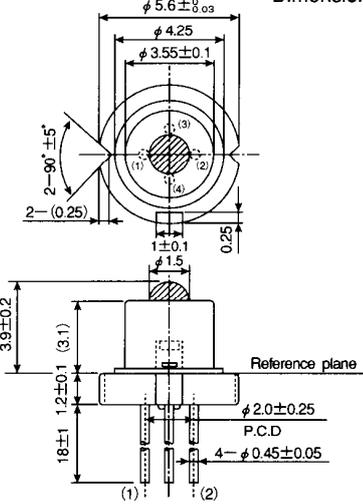
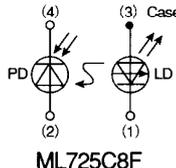
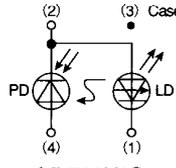


Fig.4 Fiber coupling characteristics  
(ML725C8F, ML720K8S)

MITSUBISHI LASER DIODES  
ML7XX8 SERIES

InGaAsP — MQW — FP LASER DIODES

OUTLINE DRAWINGS

<p>ML701B8R</p> 	<p>Dimension : mm</p> 	
<p>ML725B8F ML720J8S</p> 	<p>Dimension : mm</p> 	 <p>ML725B8F</p>  <p>ML720J8S</p>
<p>ML725C8F ML720K8S</p> 	<p>Dimension : mm</p> 	 <p>ML725C8F</p>  <p>ML720K8S</p>